

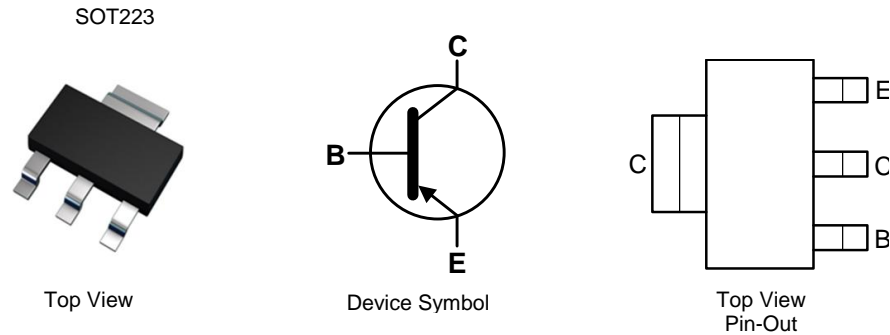
100V PNP HIGH PERFORMANCE TRANSISTOR IN SOT223

Features

- $BV_{CE0} > -100V$
- $I_C = -2A$ High Continuous Current
- $I_{CM} = -6A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < -300mV @ -1A$
- Complementary NPN Type: FZT653
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.112 grams (Approximate)

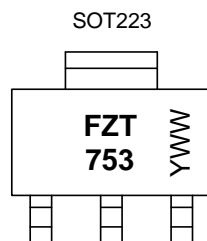


Ordering Information (Notes 4 & 5)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-----------|------------|---------|--------------------|-----------------|-------------------|
| FZT753TA | AEC-Q101 | FZT753 | 7 | 12 | 1,000 |
| FZT753QTA | Automotive | FZT753 | 7 | 12 | 1,000 |
| FZT753TC | AEC-Q101 | FZT753 | 13 | 12 | 4,000 |
| FZT753QTC | Automotive | FZT753 | 13 | 12 | 4,000 |

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



FZT 753 = Product Type Marking Code
 YYW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5= 2015)
 WW or $\bar{W}W$ = Week Code (01~53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -120 | V |
| Collector-Emitter Voltage | V _{CEO} | -100 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | I _C | -2 | A |
| Peak Pulse Current | I _{CM} | -6 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

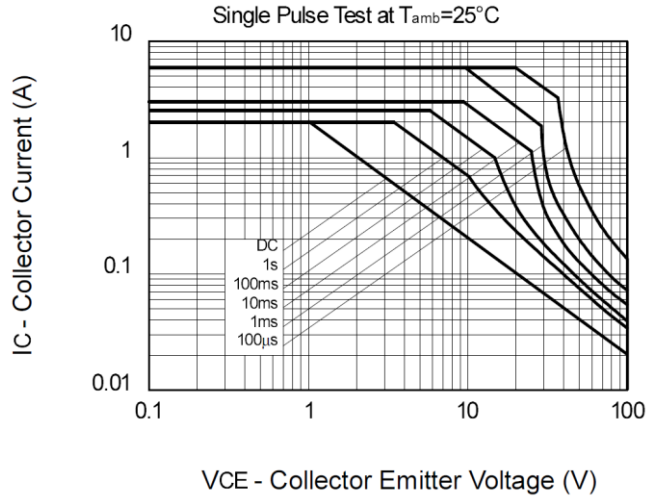
| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Power Dissipation | P _D | (Note 6) | 3.0 |
| | | (Note 7) | 2.0 |
| | | (Note 8) | 1.6 |
| | | (Note 9) | 1.2 |
| Thermal Resistance, Junction to Ambient | R _{θJA} | (Note 6) | 41.7 |
| | | (Note 7) | 62.5 |
| | | (Note 8) | 78.1 |
| | | (Note 9) | 104 |
| Thermal Resistance Junction to Lead | R _{θJL} | 12.9 | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 11)

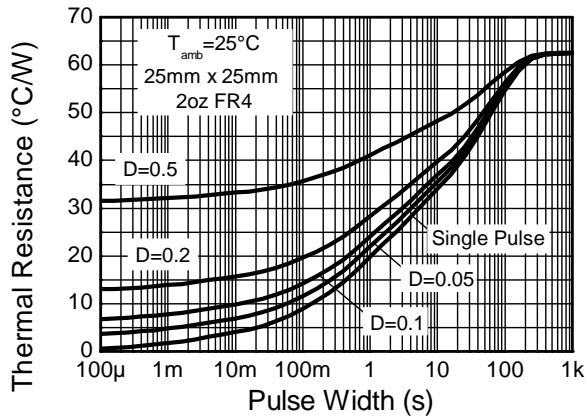
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

- Notes:
6. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 7. Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.
 8. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
 9. Same as Note 6, except the device is mounted on minimum recommended pad layout.
 10. Thermal resistance from junction to solder-point (at the end of the collector lead).
 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

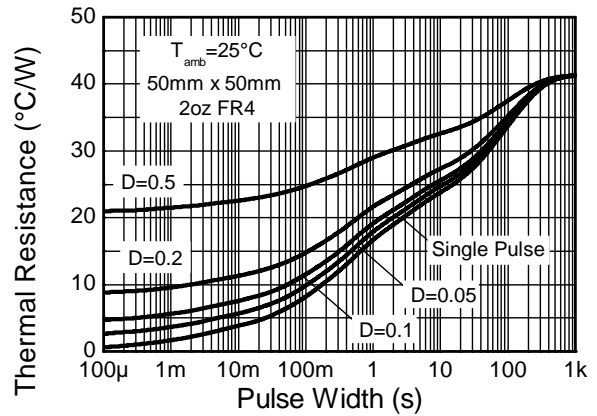
Thermal Characteristics and Derating Information



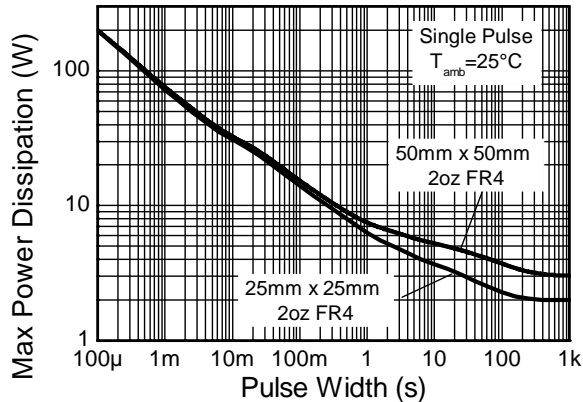
Safe Operating Area



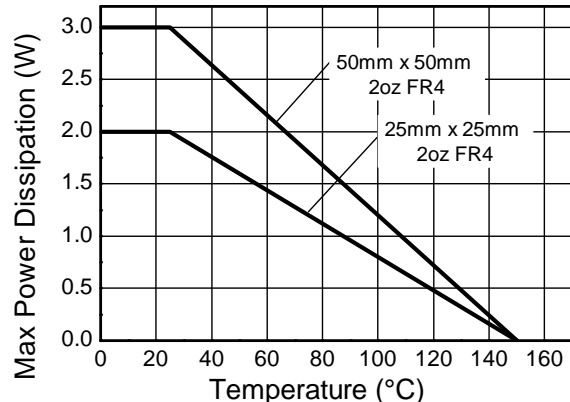
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



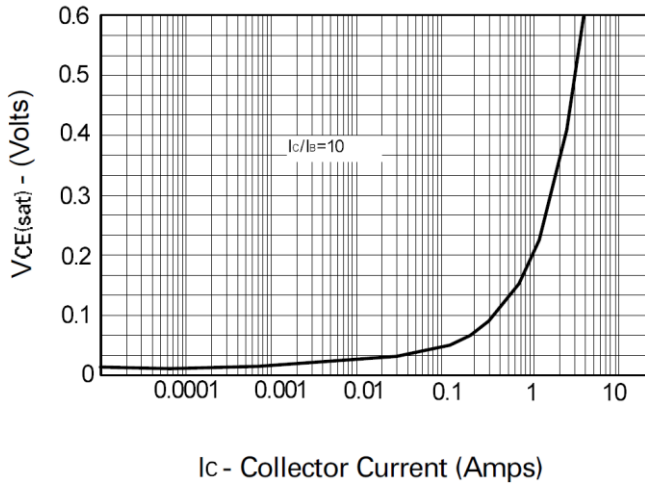
Derating Curve

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

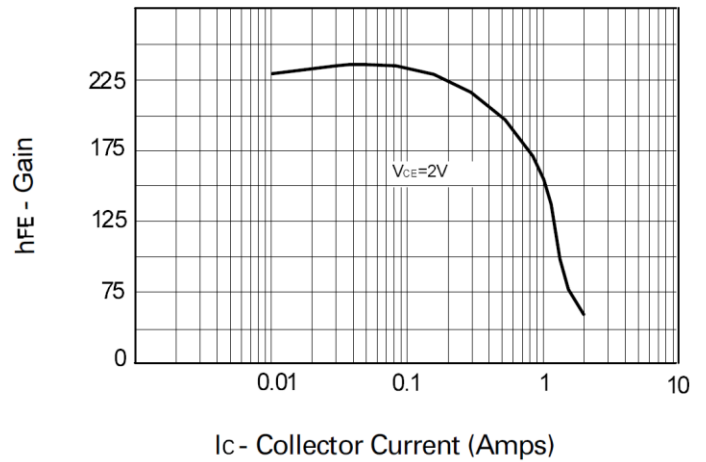
| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|------|-------|-------|------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -120 | - | - | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 12) | BV _{CEO} | -100 | - | - | V | I _C = -1mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | - | - | V | I _E = -100μA |
| Collector Cut-Off Current | I _{CBO} | - | <1 | -100 | nA | V _{CB} = -100V |
| | | - | - | -10 | μA | V _{CB} = -100V, T _A = +125°C |
| Emitter Cut-Off Current | I _{EBO} | - | <1 | -100 | nA | V _{EB} = -5.6V |
| Collector-Emitter Saturation Voltage (Note 12) | V _{CE(sat)} | - | -0.17 | -0.3 | V | I _C = -1A, I _B = -100mA |
| | | - | -0.30 | -0.5 | | I _C = -2A, I _B = -200mA |
| Base-Emitter Saturation Voltage (Note 12) | V _{BE(sat)} | - | -0.9 | -1.25 | V | I _C = -1A, I _B = -100mA |
| Base-Emitter Turn-On Voltage (Note 12) | V _{BE(on)} | - | -0.8 | -1.0 | V | I _C = -1A, V _{CE} = -2V |
| DC Current Gain (Note 12) | h _{FE} | 70 | 200 | - | - | I _C = -50mA, V _{CE} = -2V |
| | | 100 | 200 | 300 | | I _C = -500mA, V _{CE} = -2V |
| | | 55 | 170 | - | | I _C = -1A, V _{CE} = -2V |
| | | 25 | 55 | - | | I _C = -2A, V _{CE} = -2V |
| Current Gain-Bandwidth Product | f _T | 100 | 140 | - | MHz | V _{CE} = -5V, I _C = -100mA f = 100MHz |
| Turn-On Time | t _{on} | - | 40 | - | ns | V _{CC} = -10V, I _C = -500mA |
| Turn-Off Time | t _{off} | - | 600 | - | ns | I _{B1} = -I _{B2} = -50mA |
| Output Capacitance | C _{obo} | - | - | 30 | pF | V _{CB} = -10V, f = 1MHz |

Note: 12. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

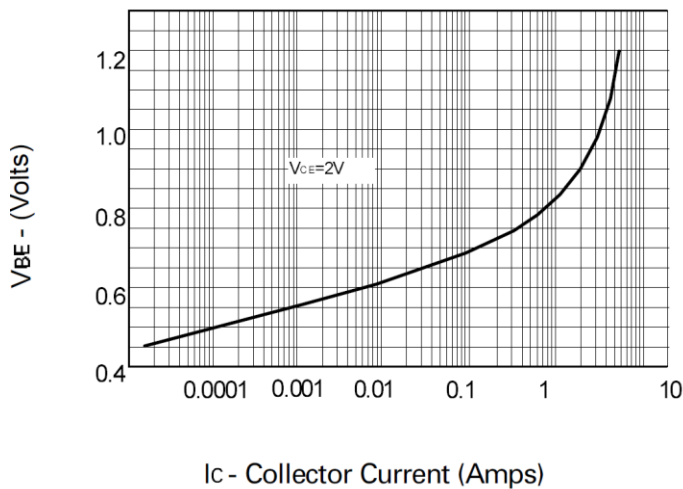
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



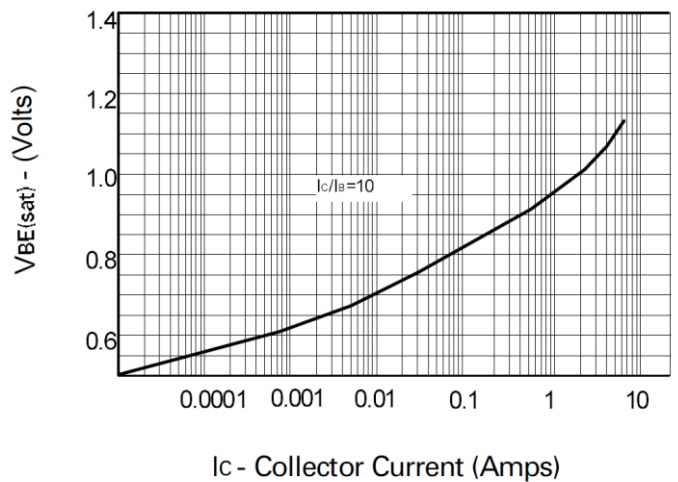
VCE(sat) v IC



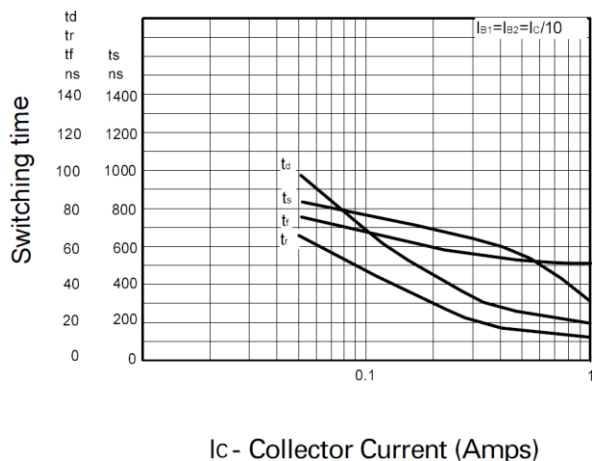
hFE v IC



VBE(on) v IC



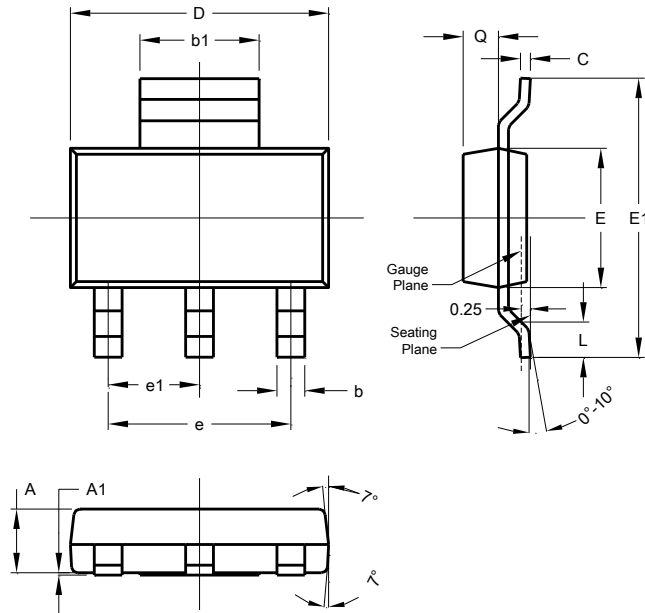
VBE(sat) v IC



Switching Speeds

Package Outline Dimensions

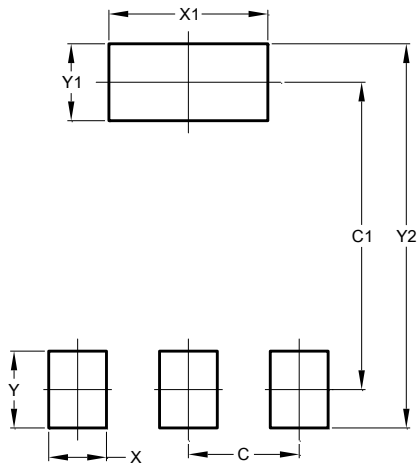
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| SOT223 | | | |
|----------------------|-------|------|------|
| Dim | Min | Max | Typ |
| A | 1.55 | 1.65 | 1.60 |
| A1 | 0.010 | 0.15 | 0.05 |
| b | 0.60 | 0.80 | 0.70 |
| b1 | 2.90 | 3.10 | 3.00 |
| C | 0.20 | 0.30 | 0.25 |
| D | 6.45 | 6.55 | 6.50 |
| E | 3.45 | 3.55 | 3.50 |
| E1 | 6.90 | 7.10 | 7.00 |
| e | - | - | 4.60 |
| e1 | - | - | 2.30 |
| L | 0.85 | 1.05 | 0.95 |
| Q | 0.84 | 0.94 | 0.89 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 2.30 |
| C1 | 6.40 |
| X | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| C2 | 8.00 |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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